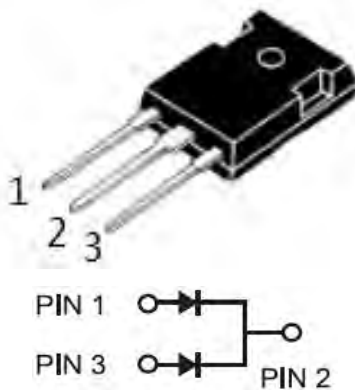


Trench MOS Barrier Schottky Rectifier

247
TSR40L45PT



Features

- Advanced trench technology
- Low forward voltage drop
- Low power losses
- High efficiency operation
- Lead Free Finish, RoHS Compliant

Applications

- DC/DC Converters
- AC/DC Adaptors
- Switching Power Supplies
- Freewheeling Diodes

Maximum ratings and electrical characteristics (T_J = 25°C unless otherwise noted)

Parameter		Symbol	Limit		Unit
Maximum repetitive peak reverse voltage		VRRM	45		V
Maximum average forward rectified current	device	IF(AV)	40		A
	per diode		20		
Peak forward surge current 8.3 ms single half sine- wave superimposed on rated load per diode		IFSM	320		A
Operating junction and storage temperature range		TJ, TSTG	-50 to +150		°C
Typical thermal resistance per leg	TO-247	RθJC	2		°C/W
Instantaneous forward voltage per diode			TYP.	MAX.	V
	IF=5A	TJ=25°C	0.41	0.46	
	IF=5A	TJ=125°C	0.36	-	
	IF=20A	TJ=25°C	0.57	0.63	
	IF=20A	TJ=125°C	0.51	-	
Instantaneous reverse current per diode at rated reverse voltage	TJ=25°C	IR(2)	20	100	µA
	TJ=125°C		10	-	mA

Notes:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≦ 40 ms

TSR40

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28-NOV-2017

PACKAGE OUTLINE DIMENSIONS

Note:unit: mm

TO-247

